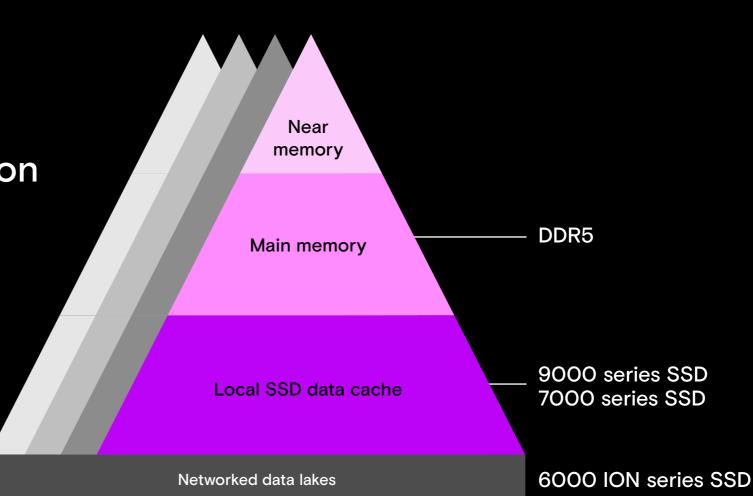


Memory and storage provide the foundation

for Al

Enabling the Al revolution through innovation and leading process technology

- 1β DRAM
- 232-Layer NAND



Memory and storage hierarchy for data center Al workloads

Micron product technology deployment advantages

High performance

For faster training and insights

DDR5

8,800MT/s²

SSDs

1.6M IOPS³

High capacity

For growing Al Large Language Models (LLMs)

DDR5 RDIMMs

128_{GB}

NVMe[™] SSDs

30.72TB³

High efficiency

With better performance per watt

Micron SSDs

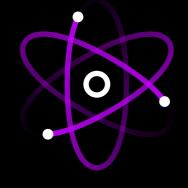
Up to 5,000x

higher performance/watt vs. legacy storage⁴

Al applications accelerated with Micron memory and storage



Deep learning



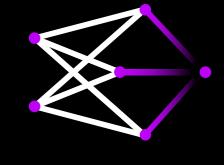
Language processing



Computer vision



Predictions & forecasting



Generative Al

www.microncpg.com/Al-solutions

- 2 Based on defined JEDEC specification
- 3 See 9400_nvme_ssd_product_brief (micron.com) for reference

the property of Micron Technology, Inc. All other trademarks are the property of their respective owners.

4 Power and performance estimates based on simulation results of workload use cases and comparison to publicly available data



1 Data rate testing estimates based on shmoo plot of pin speed performed in manufacturing test environment